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Improving the conductance of carbon nanotube networks through resonant momentum exchange

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We present a mechanism to improve the conductivity of carbon nanotube (CNT) networks by improving the conductance between CNTs of different chirality. We argue generally that a weak perturbation can greatly improve the inter-tube conductance by allowing momentum-conserving tunnelling. The mechanism is verified with a tight-binding model, allowing an investigation of its impact for a network containing a range of chiralities. We discuss practical implementations, and conclude that it may be effected by weak physical interactions, and therefore does not require chemical bonding to the CNTs.

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The remarkable electronic properties of single-walled carbon nanotubes (CNTs) make them excellent candidates for electronic devices of the future [1–5].

Whilst there exist nanoscale applications that employ CNTs individually [1, 6], considerable interest has focused on utilising bulk CNT networks, with applications including macroscopic lightweight wires [4, 7, 8] and transparent conducting films [5, 9].

Retaining the properties of individual CNTs when scaling up to the manufacture of these networks remains a significant challenge. For example, the conductivity of CNT wires is orders of magnitude lower than expected from the theoretical conductivity of individual CNTs [4, 7, 8, 10].

In a macroscopic CNT network, no single CNT spans the two ends; to traverse the device, electrons must travel through pathways involving many CNTs. The overall conductivity of a CNT network, therefore, is determined not only by the intrinsic (intra-tube) conductivity of the individual CNTs, but also by the morphology of the network [11] and by the inter-tube conductivity.

One route to improving network conductivity, therefore, is to improve inter-tube tunnelling.

There have been several studies on inter-tube transport between the ends of capped or terminated CNTs [12–14]. The tendency for CNTs to align axially in bundles however[15], together with their high aspect ratio, gives a relatively larger side-wall contact region over which inter-tube tunnelling can be improved [16]. Side-wall inter-tube conduction between perfect CNTs has been shown to be strongly suppressed for CNTs of different chirality when compared to those of the same chirality [17, 18]. This is a consequence of the sensitivity of CNT electronic structure to chirality and the requirement for both momentum and energy conservation in the tunnelling process.

As typical synthesis methods generate CNT networks with a range of chiralities, the overall conductance of the CNT network may be strongly suppressed even if the constituent CNTs are defect free, perfectly aligned and only metallic in character.

Improving side-wall conductance has proved difficult as modifications that strongly interact with the CNTs, say through covalently bonded groups [19], defects[18], or adsorbed transition metal ions[16], dramatically reduce the intrinsic conductance of individual CNTs. Weak interactions with adsorbed molecules have been shown to improve side-wall tunnelling [20], but this mechanism requires molecular states close in energy to the CNT Fermi energy and, therefore, the effectiveness of this approach is dependent on extrinsic factors that may be difficult to control.

In this Letter we consider the general problem of electron transport between CNTs of arbitrary chirality. We focus on transport between metallic CNTs, but our conclusions equally apply to semiconducting ones and to bulk inter-sheet conduction in twisted bilayer graphene[21].

Our main result is that transport between tubes of different chirality can be greatly enhanced by the presence of a *weak* external potential that achieves momentum-conserving tunnelling by enabling momentum exchange.

The fact that the potential need only be weak removes the need to modify the bonding structure of the CNTs and, hence, the intrinsic CNT conductance is unaffected. Furthermore, for a potential that varies on length-scales larger than inter-atomic bond lengths, back-scattering is forbidden and the total conductivity of the network is only improved by its presence. This potential is extrinsic to the CNTs themselves and could, for example, arise from physical interactions of the CNTs with their environment. Our analytical results are fully supported and verified by numerical tight-binding electron transport calculations.

We consider a system containing two metallic CNTs of arbitrary chirality axially aligned as shown schematically

in Fig. 1.

We denote the intrinsic tunnelling interaction between the CNTs by the operator $\hat{H}_T$.

Taking $|\psi_1\rangle$ and $|\psi_2\rangle$ to be electronic states at the Fermi energy $E_{\rm F}$ localised in each CNT, respectively, the contribution from these states to the small bias conductance $G_{1\to 2}$ can be calculated using linear response theory. To first order,

$$G_{1\to 2} = 2e^2\Gamma^{(1)}_{1\to 2}\rho_1(E_{\rm F}), \tag{1}$$

$$\Gamma^{(1)}_{1\to 2} = \frac{2\pi}{\hbar}\rho_2(E_{\rm F})\big|\langle\psi_1|\hat{H}_T|\psi_2\rangle\big|^2, \tag{2}$$

where $\Gamma^{(1)}_{1\to 2}$ is the first-order tunnelling rate between $|\psi_1\rangle$ and $|\psi_2\rangle$, and $\rho_1(E_{\rm F})$ and $\rho_2(E_{\rm F})$ are the densities of states at the Fermi level for the two CNTs.

The most relevant term in Eqn. (2) is the matrix element and its dependence on the momenta of the initial and final states and, in turn, on the chiralities of the two CNTs.

For CNT diameters typical to networks, the electronic states of the CNTs and their momenta are well described by the band-structure of graphene under a zone- folding approximation[22]. For two weakly-interacting axially-aligned CNTs we may consider two graphene Brillouin zones, each rotated by the chiral angle of the respective CNTs such that their axial momenta are aligned[17], as shown schematically in Fig. 2.

Scattering between CNT states at the Fermi energy is equivalent to scattering between the Dirac points of these rotated Brillouin zones[33], which in general have different momenta. This momentum difference, containing both axial and azimuthal components, increases as the difference in chiral angle increases.

For two CNTs that are commensurate (i.e., the ratio of the unit cell lengths is a rational fraction), the tunnelling interaction is translationally invariant and momentum must be strictly conserved[17], resulting in the remarkable conclusion that conductance between pristine CNTs of different chirality is zero.

The more common scenario, however, is that the CNTs are incommensurate, in which case translational invariance is broken [17, 24], and the requirement for momentum conservation is no longer strict. Nonetheless, it has been shown that inter-tube conductance at first order is still strongly suppressed for CNTs of different chirality due to the momentum mismatch of initial and final states [17, 24].

Irrespective of whether commensurate or not, therefore, there is a strong suppression of inter-tube transport between CNTs of mismatched chirality.

How may the inter-tube conductance between CNTs of different chirality be improved? There are two general statements that can be made about any additional tunnelling interaction: (1) it must couple two states that are spatially separated and localised on different CNTs; (2) it must accept any momentum difference between the conducting states.

We consider the effect of an extrinsic *weak* local potential $V_{\rm ext}(\mathbf{r})$ (which may be thought of as arising from the interaction of the environment with the CNTs) and consider the conditions it must satisfy to improve inter-tube conductance.

To improve conductance at first order, because the initial and final states are localised to different CNTs, $V_{\rm ext}$ would need to perturb the contact region between the CNTs where there is greatest spatial overlap.

Whilst defects[18], functionalization[16] and structural deformations[18, 25] may achieve this, they may also significantly reduce the intrinsic intra-tube conductance [19, 26] and, particularly in the case of side-wall functionalization, may increase the inter-tube separation and hence the tunnelling barrier.

In order to circumvent these problems, we consider alternative mechanisms and examine the second order scattering rate:

$$\Gamma^{(2)}_{1\to 2} = \frac{2\pi}{\hbar}\rho_2(E_{\rm F})\Big|\sum_m \frac{\langle\psi_1|\hat{H}'_T|m\rangle\langle m|\hat{H}'_T|\psi_2\rangle}{E_{\rm F}-E_m}\Big|^2, \tag{3}$$

where $\hat{H}'_T$ is the sum of the tunnelling interaction and the extrinsic potential, $\hat{H}'_T = \hat{H}_T + V_{\rm ext}$, and the sum runs over all possible states $|m\rangle$. Expanding the matrix element gives four terms

$$\begin{aligned}\langle\psi_1|\hat{H}'_T|m\rangle\langle m|\hat{H}'_T|\psi_2\rangle = \\ \langle\psi_1|\hat{H}_T|m\rangle\langle m|\hat{H}_T|\psi_2\rangle + \langle\psi_1|\hat{H}_T|m\rangle\langle m|V_{\rm ext}|\psi_2\rangle + \\ \langle\psi_1|V_{\rm ext}|m\rangle\langle m|\hat{H}_T|\psi_2\rangle + \langle\psi_1|V_{\rm ext}|m\rangle\langle m|V_{\rm ext}|\psi_2\rangle.\end{aligned} \tag{4}$$

The first and final terms correspond to an even number of inter-tube scatterings and hence do not contribute to the inter-tube conductance. The remaining two terms, however, can be large if $V_{\rm ext}$ strongly couples states in the same CNT but with different momenta.

The third term, for example, represents scattering the initial state to an intermediate state $|m\rangle$ localised within the same CNT possibly with different momentum, which then scatters into the other CNT. If $V_{\rm ext}$ is chosen such that the intermediate state has the same momentum as the final state, then inter-tube tunnelling by $\hat{H}_T$ is no longer suppressed, and can be much larger than first order tunnelling.

We validate the above mechanism with numerical results using a tight binding model. The system Hamiltonian is given by

$$\hat{H} = \sum_{\alpha=1}^{2}\hat{H}_\alpha + \hat{H}_T + \hat{V}_{\rm ext}, \tag{5}$$

where $\alpha = 1, 2$ indexes the two CNTs.

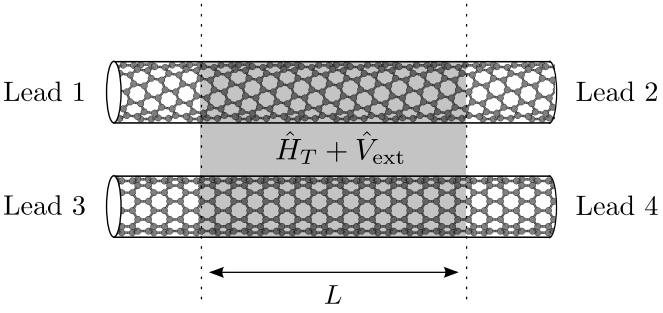

FIG. 1: The four-lead side-wall tunnelling geometry considered in this work. The tunnelling and external interaction occur in the shaded region, over a length-scale L, outside of which the leads are isolated.

The band structures of the CNTs are described using a π-orbital model including nearest neighbour hopping

$$\hat{H}_\alpha = -t_0 \sum_{\langle i,j \rangle} \left(c^\dagger_{i\alpha} c_{j\alpha} + c^\dagger_{j\alpha} c_{i\alpha} \right), \tag{6}$$

where $c^\dagger_{i\alpha}$ and $c_{i\alpha}$ are the creation and annihilation operators, respectively, for an electron on atomic site i, at position $\mathbf{r}_i$, belonging to CNT α.

The summation is performed over nearest neighbour sites $\langle i,j \rangle$ on a rolled hexagonal lattice, with interatomic bond lengths $a_{\rm C-C} = 1.415$ Å. The Fermi energy is set to zero and the hopping parameter $t_0 = 2.77$ eV.

The intrinsic tunnelling interaction between the CNTs is

$$\hat{H}_T = -\sum_{ij} t_{ij} \left(c^\dagger_{i1} c_{j2} + c^\dagger_{j2} c_{i1} \right), \tag{7}$$

where atom sites i, j are on different CNTs. Following Refs. 17 and 18, the tunnelling matrix element is

$$t_{ij} = t_\perp e^{-|\mathbf{r}_i - \mathbf{r}_j|/\delta}, \tag{8}$$

with $t_\perp = 492$ eV and $\delta = 0.5$ Å. The separation between the surfaces of the CNTs is 3.4 Å.

For the external potential, we make the ansatz $V_{\rm ext}(\mathbf{r}) = V_0 \sin(\Delta k z)$, (the z-axis is chosen as the CNT axial direction), which scatters strongly between states in the same CNT with axial momenta differing by Δk.

In the tight binding basis, this potential is approximated as diagonal

$$\hat{V}_{\rm ext} = \sum_{i\alpha} V_0 \sin(\Delta k z_{i\alpha}) c^\dagger_{i\alpha} c_{i\alpha}, \tag{9}$$

and therefore does not directly couple the two CNTs. The amplitude $V_0 = 0.1$ eV (i.e. $V_0 \ll t_0$). A physical external potential can be considered as a sum of these Fourier components. We use a damping function to mutually isolate the leads with negligible contact-induced scattering[18]. Bulk inter-tube scattering occurs over a length $L = 190$ Å (Fig. 1).

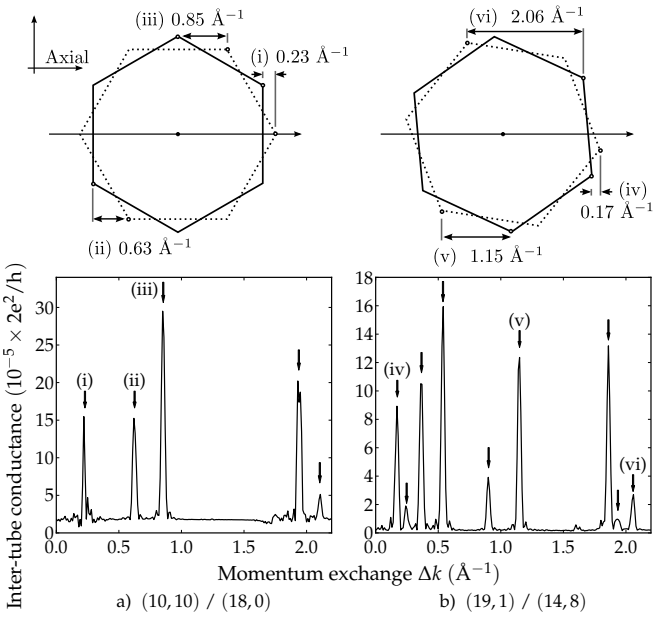

FIG. 2: Top: schematic representation of tunnelling between CNTs. The hexagons represent the first graphene Brillouin zone (BZ) for CNT pairs: a) $(10,10)/(18,0)$ (dotted line/solid line) and b) $(19,1)/(14,8)$ (dotted/ solid). Each BZ has been rotated so that the axial momentum lies along the horizontal. The metallic states are at the BZ corners. Bottom: corresponding momentum exchange dependence of inter-tube conductance at the Fermi level. Vertical arrows indicate the predicted momentum exchanges corresponding to scattering between Dirac points. For selected peaks, we show in the top panel the Dirac points involved in the scattering.

The ballistic conductance between the four semi-infinite leads is calculated using the Landauer-Büttiker formalism via a Green's function approach [27]. We define the inter-tube conductance as the sum of the conductances between a lead and the two leads of the other CNT.

By ensuring that $V_{\rm ext}$ varies only on length-scales greater than the inter- atomic bond length a_{C-C}, backscatting is vanishing [28], corresponding to a maximum momentum exchange presented in this work $\Delta k_{\rm max} = \pi / a_{\rm C-C}$. We denote the resonant momentum exchanges and potentials as $\Delta k^\star$ and $V_{\rm ext}(\Delta k^\star)$.

In Fig. 2 we plot for two CNT pairs the inter-tube conductance at the Fermi energy as a function of the momentum exchange Δk. The results are typical for CNT pairs with low intrinsic inter-tube conductance. We observe resonant peaks where the inter-tube conductance increases greatly. The momentum exchanges Δk correspond precisely to the axial momentum difference between Dirac points. We indicate these predicted positions with arrows and show for selected peaks (Fig. 2, top) the corresponding Dirac point scatterings.

The relative peak amplitudes are dependent on the

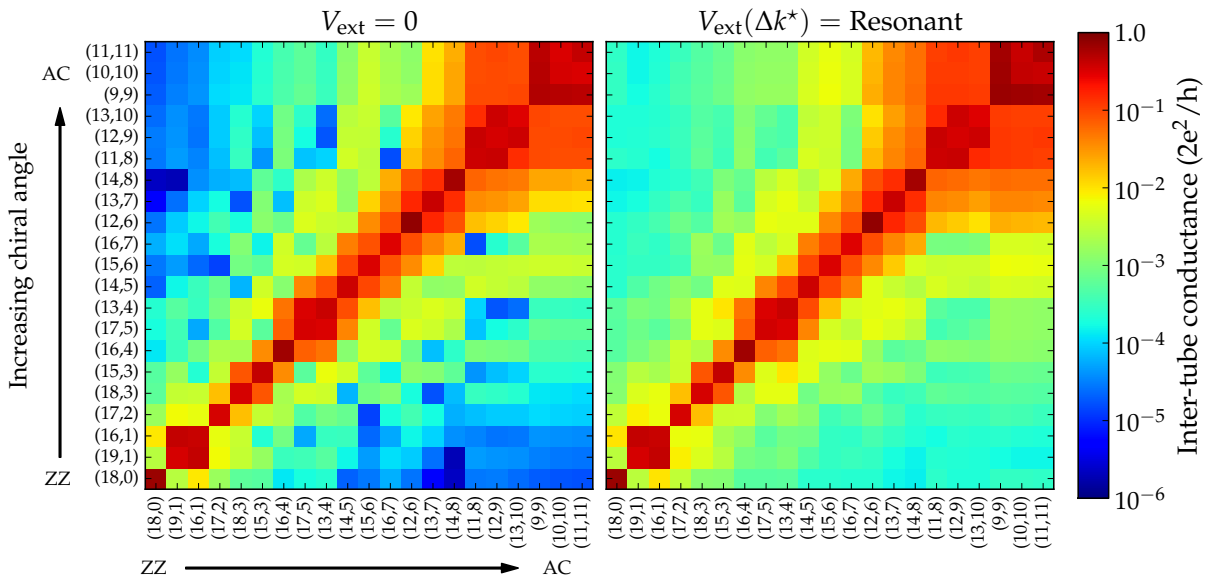

FIG. 3: The inter-tube conductance between all pairs of metallic CNTs in the diameter range $1.2 - 1.6$ nm. Left: intrinsic conductance $V_{\rm ext} = 0$; right: maximum enhanced conductance ($V_{\rm ext}$ resonant). The CNTs are ordered by increasing chiral angle and labelled by the (n, m) chiral indices.

form of the tight binding model and the spatial forms and energies of the intermediate states. Off momentum-resonance, the inter-tube conductance is unaffected by the weak potential, but for low momentum exchanges there is no decrease in the intra-tube conductance[29].

A similar momentum resonance occurs between pairs of semiconductor CNTs [29].

Realistic CNT networks are compositionally disordered in the sense that they contain CNTs with a range of chiralities.

The left panel of Fig. 3 shows the intrinsic inter-tube conductance ($V_{\rm ext} = 0$) at the Fermi energy between all pairs of metallic CNTs in the diameter range $1.2-1.6$ nm.

Where both CNTs are chiral, we show the conductance only for CNTs of opposite handedness; quantitatively equivalent results are obtained for pairs of CNTs of the same handedness[29]. The CNTs are ordered by increasing chiral angle.

From the peak along the diagonal, it is evident that inter-tube conductance is large between CNTs of the same or similar chirality. As the difference in chirality between two CNTs increases, however, momentum-conserving tunnelling is not possible and inter-tube conductance is strongly suppressed.

The right panel of Fig. 3 shows the inter-tube conductance on the addition of the momentum-resonant potential $V_{\rm ext}(\Delta k^\star)$, at which the inter-tube conductance is a maximum.

The conductance between CNTs of the same chirality is unaffected and remains high, whilst there is a strong enhancement for CNTs of different chirality.

For different CNT pairs the inter-tube conductance is maximised by different momentum exchanges $\Delta k^\star$ (see, e.g., Fig. 2), which are found to be distributed uniformly across a broad range of momentum [29]. The external potential, therefore, should contain a wide range of resonant momenta to improve the conductance of a network consisting of a wide range of CNT chiralities.

Finally, we consider this mechanism at energies away from the Fermi level. As a result of the linear dispersion relations around the Dirac points, for states travelling in the same direction the momentum exchange is resonant over a wide band of energies around the Fermi level. This is shown in Fig. 4 where we plot the transmission spectrum between leads 1 and 4. (Transmission between leads 1 and 3 is resonant at the Fermi energy only[29].) This mechanism is therefore insensitive to the small band gap in non-armchair metallic CNTs [30] and applies to doped CNT networks.

To summarise our results, we present a mechanism to improve the side-wall inter- tube conductance between CNTs of different chirality. We find that whilst the best method is to reduce the range of chiralities present, significant improvements can be made with a weak external potential allowing momentum exchange with the environment, promoting momentum conserving scattering.

By ensuring that the potential varies slowly compared to the inter-atomic distance, back-scattering is

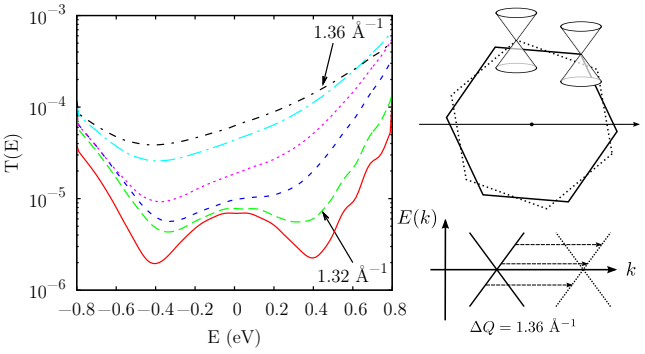

FIG. 4: Left: the transmission between leads 1 and 4 for the $(12, 9)/(13, 4)$ CNT pair as a function of electron energy for $\hat{V}_{\text{ext}} = 0$ (solid red), and for momentum transfer increasing in steps of 0.01 Å^{-1} from $\Delta k = 1.32$ Å^{-1} (dashed green) to $\Delta k = 1.36$ Å^{-1} (dot-dashed black) where momentum- resonance occurs. Transmission increases as resonance is approached. The Fermi energy is zero. Right: the Dirac points involved in this resonance, and the projection of the dispersion relation onto the axial momentum axis. The momentum exchange, indicated by the arrows, is resonant over a wide range of energies around the Fermi level.

vanishing[28], and as the mechanism is second order, the perturbation can be localised away from the contact region. Chemical bonding is not required, and instead weaker, long-range physical interactions can be utilised. Possible candidates include electrostatic influences of adsorbed molecules; substrate surface reconstructions; Moiré patterns induced in multi-walled CNTs [31]; phonon-assisted tunnelling; and polymer-wrapped CNTs[32]. Indeed, enhancements due to this mechanism may have already been observed experimentally, and this work improves our understanding of, and mechanisms to improve, the conductance of CNT networks.

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